

2STN2540-A

Low voltage fast-switching PNP power bipolar transistor

Features

- The device is qualified for automotive application
- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed
- Surface mounting device in medium power SOT-223 package

Applications

- Emergency lighting
- LED
- CCFL drivers (back lighting)
- Voltage regulation
- Relay driver

Description

The device in a PNP transistor manufactured using new "PB-HCD" (Power Bipolar High Current Density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

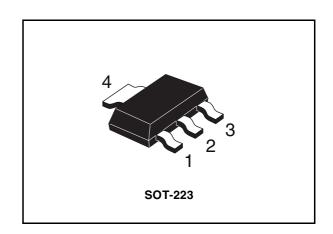


Figure 1. Internal schematic diagram

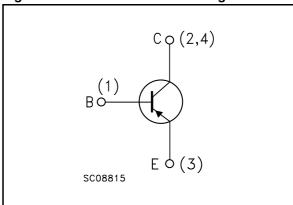


Table 1. Device summary

Order code	Marking	Package	Packaging
2STN2540-A	N2540	SOT-223	Tape & reel

Electrical ratings 2STN2540-A

1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-40	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-40	V
V _{EBO}	Emitter-base voltage ($I_C = 0$)	-6	V
I _C	Collector current	-5	Α
I _{CM}	Collector peak current (t _P < 5ms)	-10	Α
I _{BM}	Base peak current (t _P < 5ms)	-2	Α
P _{tot}	Total dissipation at T _{amb} = 25°C	1.6	W
T _{stg}	Storage temperature	-65 to 150	°C
T _J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbo	Parameter	Value	Unit
R _{thj-amb}	Thermal resistance junction-amb max	78	°C/W

^{1.} Device mounted on PCB area of 1cm²

2 Electrical characteristics

 $(T_{case} = 25 \, ^{\circ}C \text{ unless otherwise specified})$

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E =0)	V _{CB} = -30 V			-0.1	μА
I _{EBO}	Emitter cut-off current (I _C =0)	V _{EB} = -5 V			-0.1	μА
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$\begin{split} & I_{C} = -0.5 \text{ A} & I_{B} = -5 \text{ mA} \\ & I_{C} = -1 \text{ A} & I_{B} = -10 \text{ mA} \\ & I_{C} = -2 \text{ A} & I_{B} = -200 \text{ mA} \\ & I_{C} = -5 \text{ A} & I_{B} = -500 \text{ mA} \end{split}$		-80 -120 -140 -350	-120 -180 -200 -450	mV mV mV
V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C = -5 A I _B = -500 mA			-1.3	V
V _{BE(on)} (1)	Base-emitter on voltage	V _{CE} = -2 V I _C = -2 A			-1.25	V
h _{FE} ⁽¹⁾	DC current gain	$\begin{split} I_{C} &= -0.5 \text{ A} & V_{CE} &= -2 \text{ V} \\ I_{C} &= -1 \text{ A} & V_{CE} &= -2 \text{ V} \\ I_{C} &= -2 \text{ A} & V_{CE} &= -2 \text{ V} \\ I_{C} &= -5 \text{ A} & V_{CE} &= -2 \text{ V} \end{split}$	250 200 150 50			
C _{CBO}	Collector-base capacitance	$I_E = 0$ $V_{CB} = -10 \text{ V}$ f = 1MHz		80		pF
t _{on} t _s	Resistive load Turn-on time Storage time Fall time	$I_C = -1 \text{ A}$ $V_{CC} = -10 \text{ V}$ $-I_{B1} = I_{B2} = -0.1 \text{ A}$ $T_p = 30 \mu\text{A}$		75 426 62		ns ns ns

^{1.} Pulsed duration = 300 µs, duty cycle ≤1.5%

Electrical characteristics 2STN2540-A

2.1 Electrical characteristics (curves)

Figure 2. Output characteristics

Figure 3. DC current gain

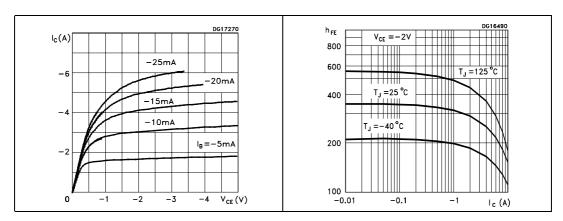


Figure 4. Collector-emitter saturation voltage

Figure 5. Base-emitter saturation voltage

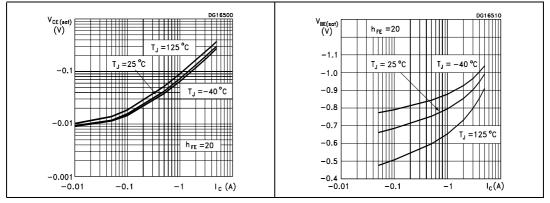
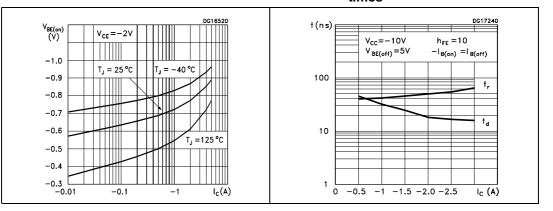


Figure 6. Base-emitter on voltage

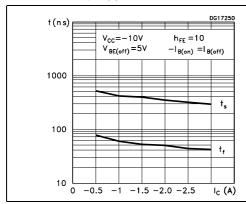
Figure 7. Resistive load switching times

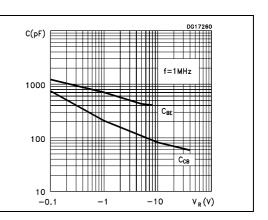


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Figure 8. Resistive load switching times

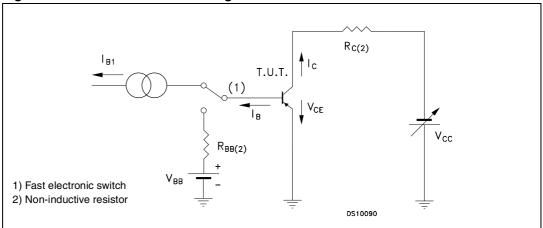
Figure 9. Capacitance





2.2 Test circuit

Figure 10. Resistive load switching test circuit



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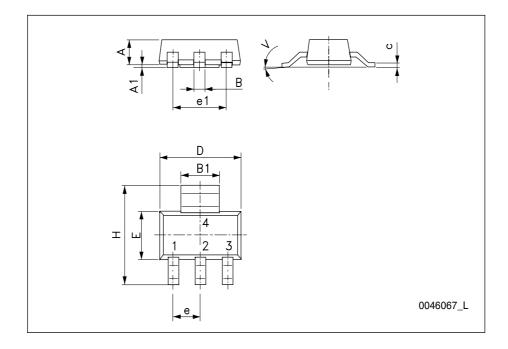
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

Figure 11. Package mechanical data

SOT-223 mechanical data

DIM.		mm.				
	min.	typ	max.			
Α			1.80			
A1	0.02		0.1			
В	0.60	0.70	0.85			
B1	2.90	3.00	3.15			
С	0.24	0.26	0.35			
D	6.30	6.50	6.70			
е		2.30				
e1		4.60				
E	3.30	3.50	3.70			
Н	6.70	7.00	7.30			
V			10 °			



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Revision history 2STN2540-A

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
23-Oct-2007	1	Initial release
15-Jan-2008	2	Updated max package dimensions in lines "B" and "c" of the package mechanical data, <i>Figure 11</i> .

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